

INTERLEAVED TRANSIENT FILTER AND METHOD

BACKGROUND

5 Embodiments of this disclosure relate generally to a filter, and more particularly, to an interleaved transient filter that removes voltage transients on its input due to radiation or due to cross talk whose duration are less than a time delay of a delay element in the filter.

Many of today's commercial integrated circuit (IC) devices may not be utilized in
10 certain situations due to radiation induced transient pulses, single particle strikes on constituent logic gates, crosstalk or other Single Event Transients (SETs). The transients may degrade the performance or cause the failure of these IC devices to function properly.

Some IC devices may use fixed delay filters that may remove voltage transients
15 from single particle strikes and from crosstalk. The fixed delay filters may be Resistor Capacitor (RC) filters, standard C-gate based fixed-delay filters where the C-gate is a source of voltage transients, or large Single Event Transient (SET) hardened C-gate based fixed-delay filters, where the C-gate has a very large drive strength to mitigate transient generation.

20 Each of the above type of fixed time delay filters may have certain issues. For example, RC filters may be very large and difficult to implement in modern commercial Complementary Metal–Oxide–Semiconductor (CMOS) technologies. Standard C-gate filters may generate transients at the output of the C-gate filter, which is the input of the logic gate that the C-gate filters are intended to protect. SET hardened C-gates may take
25 too much Application-Specific Integrated Circuit (ASIC) area. Further, the delay of all of the above mentioned filters is generally fixed for a given process, voltage and

temperature, and it is generally not possible to change the value of the delay element after fabrication. Further, it is also generally not possible to adjust the delay to get a specified delay, regardless of process, voltage and temperature variations.

Therefore, it would be desirable to provide a system and method that overcomes
5 the above.

SUMMARY

An interleaved filter circuit has a delay element configured to receive an input signal. An interleaved output buffer has a first input which receives the input signal and a
10 second input which receives the output of the delay element. An output of the interleaved output buffer is driven when the first input and the second input are at a same logic level.

An interleaved filter circuit has a delay element having an input signal and an output signal, the output signal of the delay element being at approximately a same level as the input signal after a predetermined amount of time determined by the delay element.
15 An interleaved output buffer is provided and has a first input coupled to the input signal, a second input coupled to the output signal of the delay element, an output buffer output signal being driven when the input signal and the output signal of the delay element are at a same logic level. The interleaved output buffer has a first pair of transistors coupled to the input signal, wherein the first pair of transistors are a first P-type Metal Oxide
20 Semiconductor Field Effect Transistor (PMOSFET) and first N-type Metal Oxide Semiconductor Field Effect Transistor (NMOSFET) and a second pair of transistors coupled to the output of the delay element, wherein the second pair of transistors are a second PMOSFET and a second NMOSFET, wherein the first NMOSFET is interleaved with the second NMOSFET and the first PMOSFET is interleaved with the second
25 PMOSFET.

A method for filtering Single Event Transients (SETs) comprising: providing an output buffer having a first pair of transistors wherein the first pair of transistors are a first PMOSFET and first NMOSFET and a second pair of transistors wherein the second pair of transistors are a second PMOSFET and a second NMOSFET, sending an input signal
5 to the first pair of transistors, delaying the input signal by a predetermined amount of time to the second pair of transistors to form a delayed input signal, and driving an output buffer output signal when the input signal and the delayed input signal are at a same logic level.

According to an aspect of the present disclosure there is provided an interleaved
10 filter circuit, comprising a delay element configured to receive an input signal, and an interleaved output buffer having a first input which receives the input signal, a second input which receives the output of the delay element, an output of the interleaved output buffer driven when the first input and the second input are at a same logic level.

Optionally, the interleaved filter interleaved output buffer comprises a first pair of
15 transistors coupled to the input signal, and a second pair of transistors coupled to the output of the delay element wherein the first pair of transistors and the second pair of transistors are interleaved.

Optionally, the interleaved filter circuit interleaved output buffer comprises a first pair of transistors coupled to the input signal, wherein the first pair of transistors are a
20 first P-type transistor and a first N-type transistor, and a second pair of transistors coupled to the output of the delay element, wherein the second pair of transistors are a second P-type transistor and a second N-type transistor, wherein the first N-type transistor and the second N-type transistor are interleaved and the first P-type transistor and the second P-type transistor are interleaved.

25 Optionally, the interleaved filter circuit interleaved output buffer comprises a first

pair of transistors coupled to the input signal, wherein the first pair of transistors are a first PMOSFET and first NMOSFET, and a second pair of transistors coupled to the output of the delay element, wherein the second pair of transistors are a second PMOSFET and a second NMOSFET, wherein the first NMOSFET is interleaved with the second NMOSFET and the first PMOSFET is interleaved with the second PMOSFET.

Optionally, the interleaved filter circuit delay element provides a fixed time delay.

Optionally, the interleaved filter circuit delay element provides a programmable time delay.

Optionally, the interleaved filter circuit delay element provides a user selected time delay.

Optionally, the interleaved filter circuit delay element comprises a multiplexer, and a plurality of cascaded delay elements, an output of each of the plurality of cascaded delay elements coupled to the multiplexer.

Optionally, the interleaved filter circuit delay element comprises a multiplexer, and a programmable delay element coupled to the multiplexer, the output of the delay element being determined by a programmable delay amount selected for the programmable delay element. Preferably the interleaved filter circuit programmable delay element comprises a plurality of transistor stacks, and a current mirror to control an amount of tail current flowing through the programmable delay element.

According to an aspect of the present disclosure there is provided an interleaved filter circuit, comprising a delay element having an input signal and an output signal, the output signal of the delay element being at approximately a same level as the input signal after a predetermined amount of time determined by the delay element, an interleaved output buffer having a first input coupled to the input signal, a second input coupled to the output signal of the delay element, an output buffer output signal being driven when

the input signal and the output signal of the delay element are at a same logic level, wherein the interleaved output buffer comprises a first pair of transistors coupled to the input signal, wherein the first pair of transistors are a first PMOSFET and first NMOSFET, and a second pair of transistors coupled to the output of the interleaved output buffer, wherein the second pair of transistors are a second PMOSFET and a second NMOSFET wherein the first NMOSFET is interleaved with the second NMOSFET and the first PMOSFET is interleaved with the second PMOSFET.

Optionally, the interleaved filter circuit delay element provides a fixed time delay.

Optionally, the interleaved filter circuit delay element provides a programmable time delay.

Optionally, the interleaved filter circuit delay element provides a user selected time delay.

Optionally, the interleaved filter circuit delay element comprises a multiplexer, and a plurality of cascaded delay elements, wherein each of the plurality of cascaded delay elements has an output, and wherein the output of each of the plurality of cascaded delay elements is coupled to the multiplexer.

Optionally, the interleaved filter circuit delay element comprises a multiplexer, and a programmable delay element coupled to the multiplexer, the output of the delay element being determined by a programmable delay amount selected for the programmable delay element. Preferably the interleaved filter circuit programmable delay element comprises a plurality of transistor stacks, and a current mirror to control an amount of tail current flowing through the programmable delay element.

According to an aspect of the present disclosure there is provided a method for filtering Single Event Transients (SETs), the method comprising providing an output buffer having a first pair of transistors wherein the first pair of transistors are a first

PMOSFET and first NMOSFET and a second pair of transistors wherein the second pair of transistors are a second PMOSFET and a second NMOSFET, the first and second NMOSFETs being interleaved, the first and second PMOSFETs being interleaved, sending an input signal to the first pair of transistors, sending the input signal which is
5 delayed by a predetermined amount of time to the second pair of transistors, and driving an output buffer output signal when the input signal and the delayed input signal are at a same logic level.

Optionally, sending the input signal which is delayed by a predetermined amount of time to the second pair of transistors comprises sending the input signal to a delay
10 element. Preferably the delay element is programmable.

The features, functions, and advantages may be achieved independently in various embodiments of the disclosure or may be combined in yet other embodiments.

BRIEF DESCRIPTION OF THE DRAWINGS

Embodiments of the disclosure will become more fully understood from the detailed description and the accompanying drawings, wherein:

5 **Figure 1** is a simplified schematic of an interleaved transient filter;

Figure 2 is a simplified layout showing a position of transistors used in a C-gate for the interleaved transient filter of **Figure 1**;

Figure 3 is another simplified schematic of an interleaved transient filter;

Figure 4 is a simplified schematic of the interleaved transient filter of **Figure 3**,
10 showing one implementation of a delay circuit; and

Figure 5 is a simplified layout showing a position of transistors used in a C-gate for the interleaved transient filter of **Figure 3** and **4**;

Figure 6 is another simplified schematic of an interleaved transient filter;

Figure 7 is a simplified schematic of the interleaved transient filter of **Figure 6**,
15 showing one implementation of a delay circuit; and

Figure 8 is a simplified layout showing a position of transistors used in a C-gate for the interleaved transient filter of **Figure 3** and **4**.

DETAILED DESCRIPTION

20 Referring to **Figure 1** and **2**, an interleaved transient filter **10** (hereinafter filter **10**) may be described. The filter **10** may be configured to remove voltage transients on an input **12** of the filter **10** due to radiation Single Event Transient (SETs) or due to cross talk whose duration may be less than a delay of a delay element **20** in the filter **10**.

 The filter **10** may send an input signal **A** on input **12** to an input buffer **14**. In the
25 present embodiment, the input buffer **14** may be formed of a pair of transistors **16** and **18**.

The pair of transistors **16** and **18** may be complementary MOSFETs. As shown, the transistor **16** may be a P-type transistor such as a P-type MOSFET, while the transistor **18** may be an N-type transistor such as an N-type MOSFET.

When the input signal **A** is a high signal, transistor **18** may turn on and send the
5 input signal **A** along two paths, path **1** having signal **A1** and path **2** having signal **A2**.
Similarly, when the input signal **A** is a low signal, transistor **16** may turn on and send the
input signal **A** along two paths, path **1** having signal **A1** and path **2** having signal **A2**.
Path **2** may include a delay element **20**. The two signals **A1** and **A2** along path **1** and path
2 respectively may be sent to inputs **24A** and **24B** of a logic element **22**. The logic
10 element **22** may be a C-gate **22A**.

When the signals **A1** and **A2** sent to inputs **24A** and **24B** of the C-gate **22A** match,
the C-gate **22A** may act as an inverter. When the signals **A1** and **A2** sent to inputs **24A**
and **24B** of the C-gate **22A** do not match, the C-gate **22A** may not drive its output (high
impedance state), and the output of the C-gate **22A** may maintain its current value.

15 In the embodiment shown, the C-gate **22A** may be comprised of two series PMOS
transistors **26**, **28** and two series NMOS transistors **30**, **32**. Each input **24A** and **24B** of
the C-gate **22A** controls the gate of one PMOS transistor **26** or **28** and one NMOS
transistor **30** or **32**. In the embodiment shown, the input **24A** can control the gate of
PMOS transistor **26** and the gate of NMOS transistor **32**. The input **24B** can control the
20 gate of PMOS transistor **28** and the gate of NMOS transistor **30**.

To generate an SET at an output of the filter **10**, a radiation particle would
generally have to strike either both series NMOS transistors **30**, **32**, or both series PMOS
transistors **26**, **28**, depending on the input signal **A** to the filter **10**. The C-gate PMOS
transistors **26**, **28** and NMOS transistors **30**, **32** may be interleaved to provide enough
25 separation to mitigate possible SETs occurring when a radiation particle strikes two

transistor sites.

Current Silicon-On-Insulator (SOI) technologies may have very thin epitaxial silicon layers on top of the buried oxide (BOX), generally less than 100 nm starting at the 90-nm process node. Consequently, the spacing needed to reduce double-node strikes to an acceptable level may be approximately 0.5 microns, which may be attained by interleaving the PMOS transistors **26, 28** and the NMOS transistors **30, 32** in the C-gate **22A**. The delay element **20** may be placed between the interleaved PMOS transistors **26, 28**, and between the interleaved NMOS transistors **30, 32** in the C-gate **22A**, in order to achieve the desired node spacing without any wasted space.

As may be seen in **Figure 1**, a first implementation of the filter **10** may use a delay element **20** which is a fixed delay element **20A**. The fixed delay element **20A** may be comprised of a plurality of series connected transistor delay circuits **34**. The duration of the fixed delay element **20A** may be selected during the design phase of an Application Specific Integrated Circuit (ASIC). The delay time may be a function of process, voltage and temperature. For instance, if the ASIC is manufactured in a slow corner the delay may be greater, but commensurate with the type of transients generated by the logic circuits in the ASIC.

Referring now to **Figures 3-5**, a second implementation of the filter **10'** may be shown. Like the filter **10**, the filter **10'** may send an input signal **A** to an input buffer **14**. In the embodiment shown, the input buffer **14** may be formed of a pair of transistors **16** and **18**. The pair of transistors **16** and **18** may be complementary MOSFETS. The transistor **16** may be a P-type MOSFET while the transistor **18** may be an N-type MOSFET.

When the input signal **A** is a high signal, transistor **18** may turn on and send the input signal **A** along two paths, path **1** having signal **A1** and path **2** having signal **A2**.

Similarly, when the input signal **A** is a low signal, transistor **16** may turn on and send the input signal **A** along two paths, path **1** having signal **A1** and path **2** having signal **A2**. Path **2** may include a delay element **20'**. The two signals **A1** and **A2** along path **1** and path **2** respectively may be sent to inputs **24A** and **24B** of a logic element **22**. The logic
5 element **22** may be a C-gate **22A**.

When the signals **A1** and **A2** sent to inputs **24A** and **24B** of the C-gate **22A** match, the C-gate **22A** may act as an inverter. When the signals **A1** and **A2** sent to inputs **24A** and **24B** of the C-gate **22A** do not match, the C-gate **22A** may not drive its output (high impedance state), and the output of the C-gate **22A** may maintain its current value.

10 In the embodiment shown, the C-gate **22A** may be comprised of two series PMOS transistors **26**, **28** and two series NMOS transistors **30**, **32**. Each input **24A** and **24B** of the C-gate **22A** controls the gate of one PMOS transistor **26** or **28** and one NMOS transistor **30** or **32**. In the embodiment shown, the input **24A** can control the gate of PMOS transistor **26** and the gate of NMOS transistor **32**. The input **24B** can control the
15 gate of PMOS transistor **28** and the gate of NMOS transistor **30**.

To generate an SET at an output of the filter **10'**, a radiation particle would generally have to strike either both series NMOS transistors **30**, **32**, or both series PMOS transistors **26**, **28**, depending on the input signal **A** to the filter **10'**. The C-gate PMOS transistors **26**, **28** and NMOS transistors **30**, **32** may be interleaved to provide enough
20 separation to mitigate possible SETs occurring when a radiation particle strikes two transistor sites.

As described above, current SOI technologies may have very thin epitaxial silicon layers on top of the buried oxide (BOX), generally less than 100 nm starting at the 90-nm process node, so the spacing needed to reduce double-node strikes to an acceptable level
25 may be approximately 0.5 microns. This may be attained by interleaving the PMOS

transistors **26, 28** and the NMOS transistors **30, 32** in the C-gate **22A**. Similar to delay element **20**, the delay element **20'** may also be placed between the interleaved PMOS transistors **26, 28**, and between the interleaved NMOS transistors **30, 32** in the C-gate **22A**, in order to achieve the desired node spacing without any wasted space.

5 As may be seen in **Figures 3 and 4**, the delay element **20'** is a selectable delay element **20B**. The selectable delay element **20B** may be comprised of a plurality of fixed delay circuits **36**. Each fixed delay circuits **36** may be comprised of series connected transistor delay circuits **34** similar to that shown for the fixed delay element **20A** shown in **Figure 1**. The duration of each fixed delay circuit **36** may be selected during the
10 design phase of an ASIC. The delay may be a function of process, voltage and temperature.

Each of the fixed delay circuits **36** may be coupled to a multiplexer **38**. The fixed delay circuits **36** may be placed serially back to back with the output of each fixed delay circuit **36** coupled to an input of the multiplexer **38** and to the input of the subsequent
15 fixed delay circuit **36**. The output of the multiplexer **38** may be connected to the second input **24B** of the C-gate **22A**. One or more select signals **SEL** may be sent to the multiplexer **38** and may be used to configure the selectable delay element **20B** to a user selected, desired programmable time delay. The select signals **SEL** may be used to send signals to the multiplexer **38** to select which outputs from the fixed delay circuits **36** are
20 sent to the second input **24B** of the C-gate **22A**.

Referring now to **Figures 6-8**, another implementation of the filter **10''** may be shown. Like the filter **10** and **10'**, the filter **10''** may send an input signal **A** to an input buffer **14**. In the embodiment shown, the input buffer **14** may be formed of a pair of transistors **16** and **18**. The pair of transistors **16** and **18** may be complementary
25 MOSFETS. The transistor **16** may be a P-type MOSFET while the transistor **18** may be

an N-type MOSFET.

When the input signal **A** is a high signal, transistor **18** may turn on and send the input signal **A** along two paths, path **1** having signal **A1** and path **2** having signal **A2**. Similarly, when the input signal **A** is a low signal, transistor **16** may turn on and send the input signal **A** along two paths, path **1** having signal **A1** and path **2** having signal **A2**. Path **2** may include a delay element **20**". The two signals **A1** and **A2** along path **1** and path **2** respectively may be sent to inputs **24A** and **24B** of a logic element **22**. The logic element **22** may be a C-gate **22A**.

When the signals **A1** and **A2** sent to inputs **24A** and **24B** of the C-gate **22A** match, the C-gate **22A** may act as an inverter. When the signals **A1** and **A2** sent to inputs **24A** and **24B** of the C-gate **22A** do not match, the C-gate **22A** may not drive its output (high impedance state), and the output of the C-gate **22A** may maintain its current value.

In the embodiment shown, the C-gate **22A** may be comprised of two series PMOS transistors **26**, **28** and two series NMOS transistors **30**, **32**. Each input **24A** and **24B** of the C-gate **22A** controls the gate of one PMOS transistor **26** or **28** and one NMOS transistor **30** or **32**. In the embodiment shown, the input **24A** can control the gate of PMOS transistor **26** and the gate of NMOS transistor **32**. The input **24B** can control the gate of PMOS transistor **28** and the gate of NMOS transistor **30**.

To generate an SET at an output of the filter **10**", a radiation particle would generally have to strike either both series NMOS transistors **30**, **32**, or both series PMOS transistors **26**, **28**, depending on the input signal **A** to the filter **10**". The C-gate PMOS transistors **26**, **28** and NMOS transistors **30**, **32** may be interleaved to provide enough separation to mitigate possible SETs occurring when a radiation particle strikes two transistor sites.

As described above, current SOI technologies may have very thin epitaxial silicon

layers on top of the buried oxide (BOX), generally less than 100 nm starting at the 90-nm process node, so the spacing needed to reduce double-node strikes to an acceptable level may be approximately 0.5 microns. This may be attained by interleaving the PMOS transistors **26, 28** and the NMOS transistors **30, 32** in the C-gate **22A**. Similar to delay elements 20 and 20', the delay element **20"** may be placed between the interleaved PMOS transistors **26, 28**, and between the interleaved NMOS transistors **30, 32** in the C-gate **22A**, in order to achieve the desired node spacing without any wasted space.

As may be seen in **Figures 6 and 7**, the delay element **20"** is a programmable delay element **20C**. The programmable delay element **20C** may have a programmable delay unit **40** for providing a programmable delay amount. The programmable delay unit **40** may have several transistor stacks **42** and a current mirror **44** that controls the amount of tail current flowing through the programmable delay unit **40**. In this embodiment, the filter **10"** may be programmed to filter transients of a specific delay, regardless of process, voltage and temperature variability. The programmable delay unit **40** may need a minimum of three programming signals. Two signals, **S0** and **S1**, may be used to control the current bias into the current mirror **44**. A third signal, **S2**, may be used as an additional switch that gives two different configurations of the tail current in the delay element. The design is implemented with transistors of multiple threshold voltages to generate various delay bins.

While embodiments of the disclosure have been described in terms of various specific embodiments, those skilled in the art will recognize that the embodiments of the disclosure may be practiced with modifications within the spirit and scope of the claims.

What is claimed is:

1. An interleaved filter circuit, comprising:

a delay element configured to receive an input signal; and

an interleaved output buffer having a first input which receives the input signal, a
5 second input which receives the output of the delay element, an output of the interleaved
output buffer driven when the first input and the second input are at a same logic level.

2. The interleaved filter circuit in accordance with Claim 1, wherein the
interleaved output buffer comprises:

10 a first pair of transistors coupled to the input signal; and

a second pair of transistors coupled to the output of the delay element;

wherein the first pair of transistors and the second pair of transistors are
interleaved.

15 3. The interleaved filter circuit in accordance with Claim 1, wherein the
interleaved output buffer comprises:

a first pair of transistors coupled to the input signal, wherein the first pair of
transistors are a first P-type transistor and a first N-type transistor; and

a second pair of transistors coupled to the output of the delay element, wherein the
20 second pair of transistors are a second P-type transistor and a second N-type transistor;

wherein the first N-type transistor and the second N-type transistor are interleaved
and the first P-type transistor and the second P-type transistor are interleaved.

4. The interleaved filter circuit in accordance with Claim 1, wherein the
25 interleaved output buffer comprises:

a first pair of transistors coupled to the input signal, wherein the first pair of transistors are a first PMOSFET and first NMOSFET; and

a second pair of transistors coupled to the output of the delay element, wherein the second pair of transistors are a second PMOSFET and a second NMOSFET;

5 wherein the first NMOSFET is interleaved with the second NMOSFET and the first PMOSFET is interleaved with the second PMOSFET.

5. The interleaved filter circuit in accordance with Claim 1, wherein the delay element provides a fixed time delay.

10

6. The interleaved filter circuit in accordance with Claim 1, wherein the delay element provides a programmable time delay.

7. The interleaved filter circuit in accordance with Claim 1, wherein the delay
15 element provides a user selected time delay.

8. The interleaved filter circuit in accordance with Claim 1, wherein the delay element comprises:

a multiplexer; and

20 a plurality of cascaded delay elements, an output of each of the plurality of cascaded delay elements coupled to the multiplexer.

9. The interleaved filter circuit in accordance with Claim 1, wherein the delay element comprises:

25 a multiplexer; and

a programmable delay element coupled to the multiplexer, the output of the delay element being determined by a programmable delay amount selected for the programmable delay element.

5 10. The interleaved filter circuit in accordance with Claim 9, wherein the programmable delay element comprises:

 a plurality of transistor stacks; and

 a current mirror to control an amount of tail current flowing through the programmable delay element.

10

 11. An interleaved filter circuit, comprising:

 a delay element having an input signal and an output signal, the output signal of the delay element being at approximately a same level as the input signal after a predetermined amount of time determined by the delay element;

15 an interleaved output buffer having a first input coupled to the input signal, a second input coupled to the output signal of the delay element, an output buffer output signal being driven when the input signal and the output signal of the delay element are at a same logic level;

 wherein the interleaved output buffer comprises:

20 a first pair of transistors coupled to the input signal, wherein the first pair of transistors are a first PMOSFET and first NMOSFET; and

 a second pair of transistors coupled to the output of the interleaved output buffer, wherein the second pair of transistors are a second PMOSFET and a second NMOSFET;

 wherein the first NMOSFET is interleaved with the second NMOSFET and the

25 first PMOSFET is interleaved with the second PMOSFET.

12. The interleaved filter circuit in accordance with Claim 11, wherein the delay element provides a fixed time delay.

13. The interleaved filter circuit in accordance with Claim 11, wherein the
5 delay element provides a programmable time delay.

14. The interleaved filter circuit in accordance with Claim 11, wherein the delay element provides a user selected time delay.

10 15. The interleaved filter circuit in accordance with Claim 11, wherein the delay element comprises:

a multiplexer; and

a plurality of cascaded delay elements, wherein each of the plurality of cascaded delay elements has an output, and wherein the output of each of the plurality of cascaded
15 delay elements is coupled to the multiplexer.

16. The interleaved filter circuit in accordance with Claim 11, wherein the delay element comprises:

a multiplexer; and

20 a programmable delay element coupled to the multiplexer, the output of the delay element being determined by a programmable delay amount selected for the programmable delay element.

17. The interleaved filter circuit in accordance with Claim 16, wherein the
25 programmable delay element comprises:

a plurality of transistor stacks; and

a current mirror to control an amount of tail current flowing through the

programmable delay element.

18. A method for filtering Single Event Transients (SETs), the method comprising:

5 providing an output buffer having a first pair of transistors wherein the first pair of transistors are a first PMOSFET and first NMOSFET and a second pair of transistors wherein the second pair of transistors are a second PMOSFET and a second NMOSFET, the first and second NMOSFETs being interleaved, the first and second PMOSFETs being interleaved;

10 sending an input signal to the first pair of transistors;

delaying the input signal by a predetermined amount of time to the second pair of transistors to form a delayed input signal; and

driving an output buffer output signal when the input signal and the delayed input signal are at a same logic level.

15

19. The method of Claim 18, wherein delaying the input signal comprises sending the input signal to a delay element.

20. The method of Claim 18, wherein the delay element provides a fixed time
20 delay.

21. The method of Claim 18, wherein the delay element is programmable.

22. The method of Claim 21, wherein the delay element provides a user selected time delay.